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Article

TAO-DFT with the Polarizable Continuum Model

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Abstract: For the ground-state properties of gas-phase nanomolecules with multi-reference character, thermally-assisted-occupation density functional theory (TAO-DFT) has been recently found to outperform the widely used Kohn-Sham density functional theory, when the conventional exchange-correlation energy functionals are employed. Aiming to explore solvation effects on the ground-state properties of nanomolecules with multi-reference character at a minimal computational cost, we combine TAO-DFT with the polarizable continuum model (PCM). To show its usefulness, TAO-DFT-based PCM (TAO-PCM) is employed to study the electronic properties of linear acenes in three different solvents (toluene, chlorobenzene, and water). According to TAO-PCM, in the presence of these solvents, the smaller acenes should have nonradical nature, and the larger acenes should have increasing polyradical nature, showing remarkable similarities to the past findings in the gas phase.

1. Introduction

Electronic structure methods are commonly used to compute the properties of gas-phase molecules. Nonetheless, the properties of molecules in solutions can be very different from those of gas-phase molecules. Therefore, it is essentially important to understand the effects of solvents on the properties of solute molecules, especially when polar solvents are involved. While it is possible to adopt explicit solvent models (wherein solvation effects are taken into consideration by explicitly including the molecular details of each solvent molecule) [1–3], the resulting electronic structure calculations can, however, be computationally intractable in many applications.

To circumvent this difficulty, various implicit solvent models have been developed to study the properties of molecules in polarizable solvents over the past few decades. Among them, the Kirkwood-Onsager model [4–6] is perhaps the simplest one. However, the Kirkwood-Onsager (KO) model is not appropriate for non-spherical solute molecules because of its underlying assumptions.

To resolve the shortcomings of the KO model, the recently developed implicit solvent models, such as the polarizable continuum model (PCM) [1–3,7–22], have become popular due to their reasonably accurate description of solvation effects at a low computational cost. In the PCM, the solvent is modeled as a polarizable continuum (i.e., a homogeneous dielectric medium, rather than individual molecules), and the solute is placed inside a molecule-shaped cavity surrounded by the continuum solvent [1–3]; typically, the solute is treated quantum-mechanically with an electronic structure method, and the solvation effect is modeled implicitly with a PCM. In the past few years, various types of PCMs, such as the dielectric version of PCM (D-PCM) [7], conductor-like screening model (COSMO) [8], COSMO for real solvents (COSMO-RS) [9], generalized COSMO (GCOSMO) [10], conductor-like PCM (C-PCM) [11], integral equation formalism of the PCM (IEF-PCM) [12–15], surface and simulation of volume polarization for electrostatics [SS(V)PE] model [16–20], and many others [21,22] have been developed to properly describe solvation effects.

On the other hand, among the presently available electronic structure methods, Kohn-Sham density functional theory (KS-DFT) [23] has been regarded as the method of choice for predicting the ground-state properties of nanomolecules in the gas phase. Accordingly, KS-DFT-based PCM (KS-PCM) [1–3] has been widely employed for exploring the properties of nanomolecules in solutions.

However, in KS-DFT, the exact exchange-correlation (XC) energy functional remains unavailable, and the widely used XC energy functionals are approximate, and can suffer from a number of serious issues [24,25].

For instance, KS-DFT with the conventional local, semilocal, and hybrid XC energy functionals can lead to unreliable results for the ground-state properties of gas-phase molecules with multi-reference (MR) character. Therefore, it can be anticipated that the corresponding KS-PCM can also lead to incorrect solvation effects on the ground-state properties of these molecules. Typically, accurate MR electronic structure methods [26–35] are required for studying gas-phase molecules with MR character. Nonetheless, these MR methods and related PCMs [36] are computationally infeasible for nanomolecules in the gas phase and solution phase, respectively, limiting their applications only to very small molecules.

To study the ground-state properties of gas-phase nanomolecules with MR character, thermally-assisted-occupation density functional theory (TAO-DFT) [37], i.e., a density functional theory using the fractionally occupied thermally-assisted-occupation (TAO) orbitals, has been recently proposed. Since the TAO-orbital occupation numbers (TOONs) are directly produced by the Fermi-Dirac (FD) distribution function with some fictitious temperature θ , TAO-DFT, which is as efficient as KS-DFT in computational expense, appears to be a promising electronic structure method for studying gas-phase nanomolecules with MR character. Besides, the conventional local [37], semilocal [38], and hybrid [39] XC energy functionals (as defined in KS-DFT) can also be used in TAO-DFT. In addition, several TAO-DFT-extensions [40–44] have been recently developed as well. Over the last few years, TAO-DFT has been employed to explore the electronic [45–61], hydrogen storage [47,49,50], and spectroscopic [43,62,63] properties of gas-phase nanomolecules with MR character, outperforming KS-DFT with the widely used XC energy functionals. Moreover, a few recent studies [64–67] on the ground-state properties of electronic systems at absolute zero have been actually performed using an approximate TAO-DFT method (i.e., TAO-DFT without the θ -dependent energy functional [37]) at some fictitious temperature θ , which should not be confused with the Mermin-Kohn-Sham method (also called finite-temperature density functional theory (FT-DFT)) [23,68] at some finite electronic temperature due to their distinctly different physical meanings (e.g., see Refs. [37,44,58] for further discussion).

Accordingly, in this work, we combine TAO-DFT with the PCM to model solvation effects on the ground-state properties of nanomolecules with MR character. The resulting TAO-DFT-based PCM, denoted as TAO-PCM, is expected to improve upon the widely used KS-PCM for the properties of solute molecules with MR character, when solvents are involved. To show its usefulness, we also employ TAO-PCM to explore the effects of solvents on the electronic properties (the singlet-triplet energy gap, vertical electron affinity/ionization potential, fundamental gap, etc.) of n -acene (i.e., a linear acene with n aromatic rings, e.g., see Figure 1) in three different solvents (toluene, chlorobenzene, and water). Since the larger n -acenes in the gas phase have been recently found to exhibit MR character in their ground states [27,29,37,39,43–45], the larger n -acenes in solvents are also expected to exhibit MR character (as will be shown later). Furthermore, some shortcomings of KS-PCM related to the issues of MR character are found to be greatly resolved by TAO-PCM.

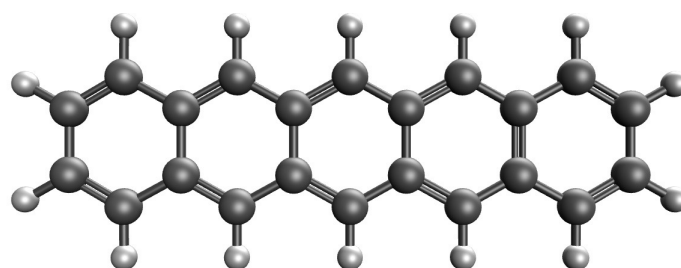


Figure 1. Geometry of 5-acene (i.e., the solute), containing five aromatic rings.

2. TAO-PCM

Consider a solute molecule (with N electrons) surrounded by solvent molecules. In the PCM [1–3,7–22], the solvent is modeled as a polarizable continuum (rather than individual molecules), and a molecule-shaped cavity, which separates the solute and the continuum solvent, is constructed (e.g., using a union of atom-centered spheres with the scaled van der Waals (vdW) radii), wherein the dielectric constant is set equal to 1 inside the cavity (as in vacuum), and is set equal to ϵ (i.e., the bulk value of the considered solvent) outside the cavity.

In TAO-PCM, the solute is treated quantum-mechanically with TAO-DFT [37], and the solvation effect is modeled implicitly with the PCM. Specifically, in the presence of the continuum solvent, the TAO-PCM solute free energy $G_{\text{TAO-PCM}}[\rho]$ is a functional of the solute electron density $\rho(\mathbf{r})$ (atomic units are adopted throughout this work):

$$G_{\text{TAO-PCM}}[\rho] = E_{\text{TAO}}[\rho] + V_{\text{NN}} + G_{\text{PCM}}[\rho], \quad (1)$$

where $E_{\text{TAO}}[\rho]$ (e.g., see Eq. (27) of Ref. [37]) is the gas-phase solute electronic energy in TAO-DFT, V_{NN} is the solute nuclear repulsion energy, and $G_{\text{PCM}}[\rho]$ (e.g., see Eq. (14) of Ref. [21]) is the solute-solvent interaction free energy in the PCM.

To obtain the solute electron density $\rho(\mathbf{r})$, the TAO-PCM self-consistent equations are given by

$$\left\{ -\frac{1}{2}\nabla^2 + v_{\text{TAO}}(\mathbf{r}) + v_{\text{PCM}}(\mathbf{r}) \right\} \psi_i(\mathbf{r}) = \epsilon_i \psi_i(\mathbf{r}). \quad (2)$$

Here, $v_{\text{TAO}}(\mathbf{r})$ (e.g., see Eq. (18) of Ref. [37]) is the gas-phase solute effective potential in TAO-DFT, and $v_{\text{PCM}}(\mathbf{r}) = \delta G_{\text{PCM}}[\rho] / \delta \rho(\mathbf{r})$ (e.g., see Eq. (17) of Ref. [21]) is the reaction potential in the PCM, and the solute electron density $\rho(\mathbf{r})$ is expressed as

$$\rho(\mathbf{r}) = \sum_i f_i |\psi_i(\mathbf{r})|^2, \quad (3)$$

where f_i (the occupation number of the i -th TAO-orbital $\psi_i(\mathbf{r})$) is generated by the FD distribution function (with some fictitious temperature θ):

$$f_i = \{1 + \exp[(\epsilon_i - \mu)/\theta]\}^{-1} \quad (4)$$

satisfying the conditions: $\sum_i f_i = N$ and $0 \leq f_i \leq 1$, with ϵ_i being the energy of the i -th TAO-orbital $\psi_i(\mathbf{r})$, and μ being the chemical potential.

For the $\theta = 0$ case, since TAO-DFT reduces to KS-DFT, TAO-PCM reduces to KS-PCM. Note also that the PCM component $G_{\text{PCM}}[\rho]$, as well as $v_{\text{PCM}}(\mathbf{r})$, which depends only on the solvent dielectric constant ϵ and the solute (electronic and nuclear) charge density [21], has the same expression in TAO-PCM as in KS-PCM. Besides, for an isolated solute molecule (i.e., $\epsilon = 1$), as $G_{\text{PCM}}[\rho] = 0$ and $v_{\text{PCM}}(\mathbf{r}) = 0$, TAO-PCM reduces to TAO-DFT, and KS-PCM reduces to KS-DFT.

3. Computational Details

We perform all calculations using the 6-31G(d) basis set with the software package of Q-Chem 4.4 [69]. As mentioned previously, in TAO-PCM, TAO-DFT is adopted for the electronic structure calculations, and the PCM is adopted for the modeling of solvent effects. In the present study, for the TAO-DFT part, we adopt TAO-LDA [37], which is TAO-DFT with the local density approximation (LDA) XC and θ -dependent energy functionals (with the suggested fictitious temperature $\theta = 7$ mhartree). Besides, for the PCM part, we adopt C-PCM [11], which has been a popular PCM due to its simplicity in formalism and implementation as well as its decent balance between efficiency and accuracy. Note also that C-PCM is an approximation of COSMO [8], and can also be regarded as the high-dielectric limit of IEF-PCM [12–15].

For the construction and discretization of solute cavity surface, the solute cavity surface [3] is formed using a union of atom-centered spheres with radii being 1.2 times the atomic vdW radii [70–72]. In addition, the switching/Gaussian (SWIG) approach is adopted for smooth cavity discretization [73,74], with 194 Lebedev grid points per atomic sphere. Furthermore, for the solvent dielectric constant ϵ , we adopt the Q-Chem default value, i.e., 2.38 for toluene, 5.62 for chlorobenzene, and 78.39 for water.

For comparison with the results of TAO-PCM (i.e., TAO-LDA/C-PCM), we also present the results of the corresponding KS-PCM (i.e., KS-LDA/C-PCM), wherein KS-LDA (i.e., KS-DFT with the LDA XC energy functional, which is the same as TAO-LDA with $\theta = 0$) is used for the electronic structure calculations, and C-PCM is used for the modeling of solvent effects.

4. Results and Discussion

4.1. Singlet-Triplet Energy Gap

Singlet-triplet energy gap (ST gap) can provide many insights on chemical processes. To obtain the ST gap of n -acene (i.e., the solute) in the continuum solvent, we fully optimize the geometries of the lowest singlet and triplet states of n -acene in the continuum solvent, using spin-unrestricted TAO-PCM (i.e., TAO-LDA/C-PCM), and subsequently, calculate the ST gap (E_{ST}) of n -acene in the continuum solvent using

$$E_{\text{ST}} = G_{\text{UT}} - G_{\text{US}}, \quad (5)$$

where G_{US} and G_{UT} are the spin-unrestricted TAO-PCM free energies (given by Equation (1)) associated with the lowest singlet and triplet states, respectively, of n -acene in the continuum solvent. For comparison, we also report the results of the corresponding KS-PCM (i.e., KS-LDA/C-PCM). As presented in Figures 2 and 3 (also see Tables S1 and S2 in the SI (supplementary information) for additional information), the ST gaps of n -acenes in three different solvents (toluene, chlorobenzene, and water) are essentially the same as those of n -acenes in the gas phase, indicating that the solvation effects play insignificant roles here. Besides, n -acenes in different media have singlet ground states for all the cases investigated. As molecules with MR character are commonly characterized by small ST gaps, similar to the gas-phase situations [37–39,43–45], in the three solvents, the larger n -acenes, which possess smaller ST gaps, are expected to have more significant MR character than the smaller n -acenes.

On the other hand, the ST gap of TAO-PCM decreases with the size of n -acene in a monotonic manner, while the ST gap of KS-PCM exhibits an unexpected increase beyond 10-acene. Therefore, we also investigate the potential causes of such discrepancies by examining the $\langle \hat{S}^2 \rangle$ values (i.e., the expectation values of the total spin-squared operator) associated with the lowest singlet and triplet states of n -acene in the continuum solvent, calculated by spin-unrestricted KS-PCM (see Tables 1 and 2). For the KS-PCM wavefunction with an artificial mixing of several spin-states (the so-called spin contamination), the respective $\langle \hat{S}^2 \rangle$ value will be larger than the exact value of $\langle \hat{S}^2 \rangle$ (i.e., 2 for the lowest triplet state and 0 for the lowest singlet state) [51,54,58,75]. Accordingly, the difference between the $\langle \hat{S}^2 \rangle$ value of KS-PCM and the exact $\langle \hat{S}^2 \rangle$ value can be regarded as a measure of the degree of spin contamination in the spin-unrestricted KS-PCM wavefunction. As shown, for the smaller n -acenes, the $\langle \hat{S}^2 \rangle$ values of KS-PCM are very close to the exact values of $\langle \hat{S}^2 \rangle$, implying that the lowest singlet and triplet states of the smaller n -acenes in different media, obtained with spin-unrestricted KS-PCM, essentially have no spin contamination. Nonetheless, for the lowest singlet states of some larger n -acenes (9-acene, 10-acene, 11-acene, 12-acene, etc.), the $\langle \hat{S}^2 \rangle$ values of KS-PCM are considerably larger than the exact $\langle \hat{S}^2 \rangle$ values, indicating that the lowest singlet states of some larger n -acenes in different media, obtained with spin-unrestricted KS-PCM, are heavily spin-contaminated. Consequently, the larger n -acenes can have MR character in the lowest singlet states, and the unexpected increase in the ST gap of KS-PCM beyond 10-acene could simply be an artifact related to spin contamination.

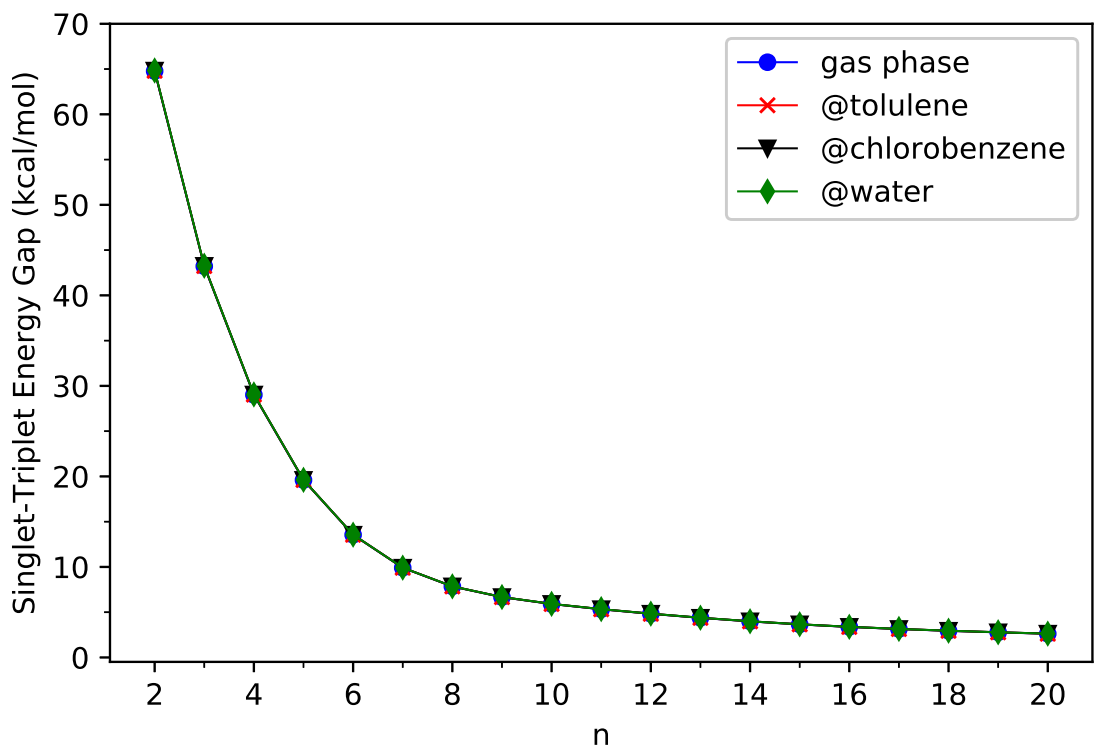


Figure 2. Singlet-triplet energy gap of *n*-acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), calculated using spin-unrestricted TAO-PCM (i.e., TAO-LDA/C-PCM).

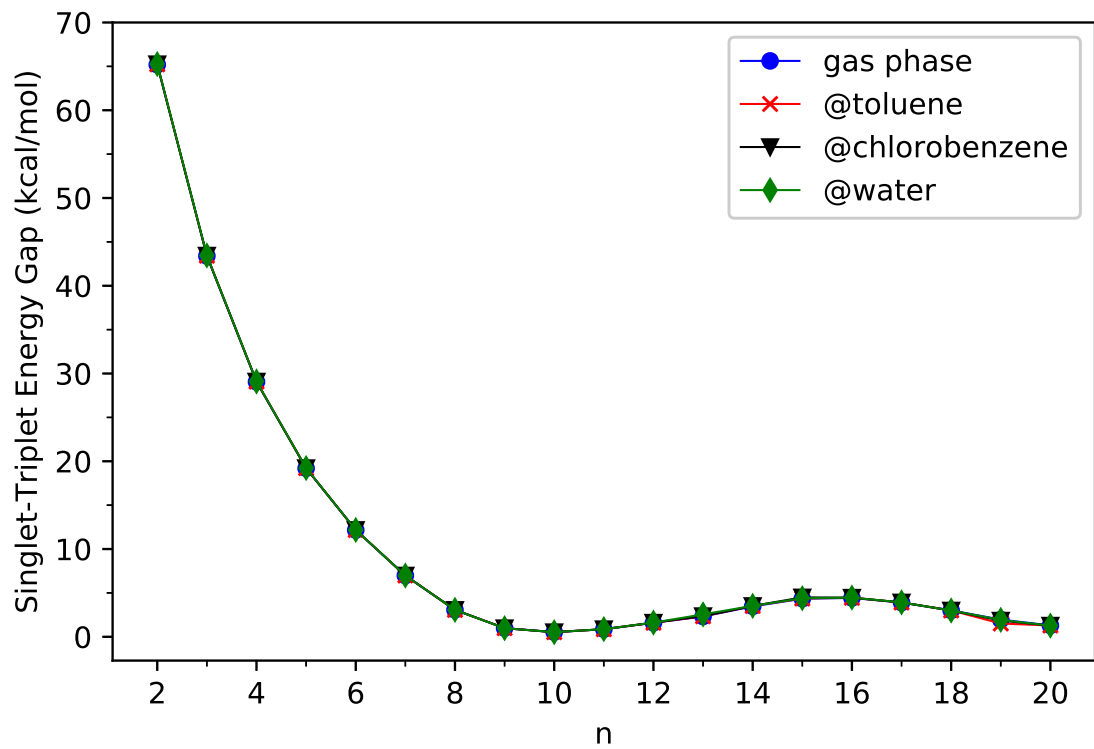


Figure 3. Singlet-triplet energy gap of *n*-acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), calculated using spin-unrestricted KS-PCM (i.e., KS-LDA/C-PCM).

Table 1. Expectation value of the total spin-squared operator ($\langle \hat{S}^2 \rangle$) for the lowest singlet state of *n*-acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), calculated using spin-unrestricted KS-PCM (i.e., KS-LDA/C-PCM). For the lowest singlet state, the exact $\langle \hat{S}^2 \rangle$ is 0.

<i>n</i>	Gas Phase	Toluene	Chlorobenzene	Water
2	0.0000	0.0000	0.0000	0.0000
3	0.0000	0.0000	0.0000	0.0000
4	0.0000	0.0000	0.0000	0.0000
5	0.0000	0.0000	0.0000	0.0000
6	0.0000	0.0000	0.0000	0.0000
7	0.0001	0.0001	0.0001	0.0001
8	0.0233	0.0298	0.0307	0.0024
9	0.8549	0.8537	0.8542	0.8563
10	1.0391	1.0389	1.0388	1.0388
11	0.9574	0.9546	0.9529	0.9514
12	0.7481	0.7415	0.7378	0.7336
13	0.0007	0.4700	0.4642	0.4602
14	0.0006	0.0005	0.0007	0.0005
15	0.0007	0.0003	0.0004	0.0012
16	0.0014	0.0007	0.0008	0.0173
17	0.0026	0.0478	0.0463	0.0584
18	0.0004	0.0007	0.0009	0.0009
19	0.8978	0.0002	0.7472	0.8890
20	1.1886	0.0008	1.1840	1.1831

Table 2. Expectation value of the total spin-squared operator ($\langle \hat{S}^2 \rangle$) for the lowest triplet state of *n*-acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), calculated using spin-unrestricted KS-PCM (i.e., KS-LDA/C-PCM). For the lowest triplet state, the exact $\langle \hat{S}^2 \rangle$ is 2.

<i>n</i>	Gas Phase	Toluene	Chlorobenzene	Water
2	2.0053	2.0052	2.0052	2.0052
3	2.0045	2.0045	2.0045	2.0045
4	2.0047	2.0047	2.0047	2.0047
5	2.0049	2.0048	2.0048	2.0048
6	2.0050	2.0050	2.0050	2.0049
7	2.0051	2.0051	2.0051	2.0051
8	2.0052	2.0052	2.0052	2.0052
9	2.0053	2.0053	2.0052	2.0052
10	2.0053	2.0053	2.0053	2.0053
11	2.0053	2.0053	2.0053	2.0053
12	2.0053	2.0053	2.0053	2.0053
13	2.0053	2.0053	2.0052	2.0052
14	2.0052	2.0052	2.0052	2.0052
15	2.0206	2.0206	2.0051	2.0207
16	2.0315	2.0312	2.0310	2.0309
17	2.0230	2.0226	2.0223	2.0220
18	2.0335	2.0331	2.0329	2.0327
19	2.0372	2.0366	2.0364	2.0362
20	2.0412	2.0406	2.0404	2.0402

In addition, we can also assess the effects of spin contamination in the lowest singlet free energies of *n*-acenes in different media, obtained with spin-unrestricted TAO-PCM and KS-PCM. Due to the spin-symmetry constraint [37–39], for the PCM with an exact electronic structure method, the lowest singlet free energy of *n*-acene in the continuum solvent, computed using the spin-restricted formalism has to be identical to that computed using the spin-unrestricted formalism. To assess whether this constraint can be obeyed in TAO-PCM, we fully optimize the geometries of the lowest singlet state

of n -acene in the continuum solvent, using spin-restricted and spin-unrestricted TAO-PCM, and subsequently, compute the E_{UR} value (i.e., the difference between the lowest spin-restricted and spin-unrestricted singlet free energies) of n -acene in the continuum solvent using

$$E_{UR} = G_{RS} - G_{US}, \quad (6)$$

where G_{RS} and G_{US} are the TAO-PCM free energies (given by Equation (1)) associated with the lowest singlet state of n -acene in the continuum solvent, computed using the spin-restricted and spin-unrestricted formalisms, respectively. For comparison, we also report the corresponding KS-PCM results. As shown in Table 3, the E_{UR} values of n -acenes in the continuum solvent, calculated by KS-PCM, are rather large for some larger n -acenes (e.g., $E_{UR} \geq 3.20$ kcal/mol for 10-acene), yielding unphysical spin-symmetry breaking effects in the corresponding spin-unrestricted KS-PCM calculations. By contrast, the E_{UR} values of n -acenes in the continuum solvent, calculated by TAO-PCM, are essentially zero for all the cases investigated, yielding essentially no unphysical spin-symmetry breaking effects in the corresponding spin-unrestricted TAO-PCM calculations.

Table 3. Difference E_{UR} (in kcal/mol) between the lowest spin-restricted and spin-unrestricted singlet free energies of n -acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), calculated using KS-PCM (i.e., KS-LDA/C-PCM).

n	Gas Phase	Toluene	Chlorobenzene	Water
2	0.00	0.00	0.00	0.00
3	0.00	0.00	0.00	0.00
4	0.00	0.00	0.00	0.00
5	0.00	0.00	0.00	0.00
6	0.00	0.00	0.00	0.00
7	0.00	0.00	0.00	0.00
8	0.00	0.00	0.00	0.00
9	0.93	0.93	0.93	0.93
10	3.26	3.23	3.21	3.20
11	1.58	1.55	1.54	1.53
12	0.66	0.64	0.63	0.62
13	0.00	0.19	0.19	0.18
14	0.00	0.00	0.00	0.00
15	0.00	0.00	0.00	0.00
16	0.00	0.00	0.00	0.00
17	0.00	0.00	0.00	0.00
18	0.00	0.00	0.00	0.00
19	0.43	0.00	0.34	0.42
20	1.09	0.00	1.08	1.08

In a word, the ST gaps of the larger n -acenes in the continuum solvent, computed using KS-PCM, can be severely influenced by spin contamination, seriously degrading the accuracy of KS-PCM in predicting the ST gaps and possibly, other electronic properties. As will be shown later, the ground states (i.e., the lowest singlet states) of the larger n -acenes in different media exhibit increasing polyradical nature, wherein KS-PCM could lead to unreliable electronic properties. Consequently, we merely present the TAO-PCM results hereafter.

4.2. Vertical Electron Affinity/Ionization Potential and Fundamental Gap

For a neutral solute molecule (with N electrons) in a continuum solvent, the free energy gained when an electron is added to the neutral solute molecule (without altering the solute geometry) is defined as the vertical electron affinity

$$EA_v = G_N - G_{N+1}, \quad (7)$$

the free energy required to remove an electron from the neutral solute molecule (without altering the solute geometry) is defined as the vertical ionization potential

$$\text{IP}_v = G_{N-1} - G_N, \quad (8)$$

and their difference is defined as the fundamental gap [38,39]

$$E_g = \text{IP}_v - \text{EA}_v = G_{N+1} + G_{N-1} - 2G_N. \quad (9)$$

In this study, G_N , G_{N+1} , and G_{N-1} are the spin-unrestricted TAO-PCM free energies (given by Equation (1)) associated with the neutral, anionic, and cationic states, respectively, of n -acene (i.e., the solute) in the continuum solvent.

Figures 4 to 6 (also see Tables S3, S4, and S5 in the SI for additional information) present the values of IP_v , EA_v , and E_g , respectively, of ground-state n -acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), obtained with spin-unrestricted TAO-PCM (i.e., TAO-LDA/C-PCM). As shown, for each solvent studied, the IP_v decreases in a monotonic manner as the size of n -acene increases. Besides, for each n -acene studied, the IP_v decreases as the solvent dielectric constant ϵ increases, indicating that less free energy is required to remove an electron from n -acene in the continuum solvent of larger ϵ . Therefore, the IP_v of n -acene is the largest in the gas phase ($\epsilon = 1$), and is the smallest in water ($\epsilon = 78.39$).

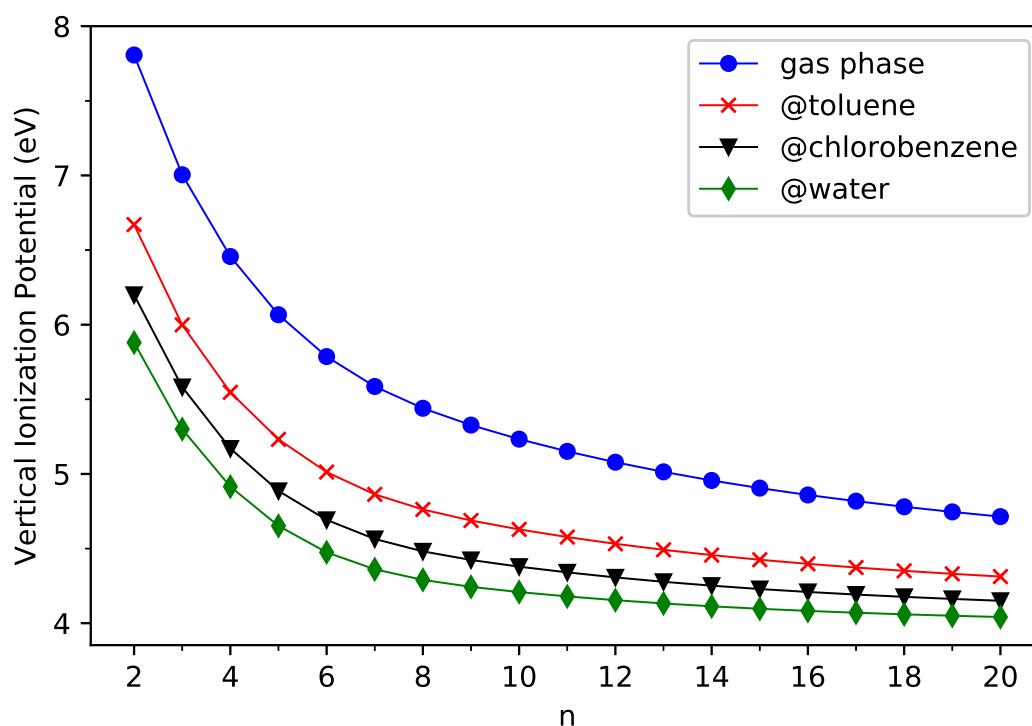


Figure 4. Vertical ionization potential for the ground state of n -acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), calculated using spin-unrestricted TAO-PCM (i.e., TAO-LDA/C-PCM).

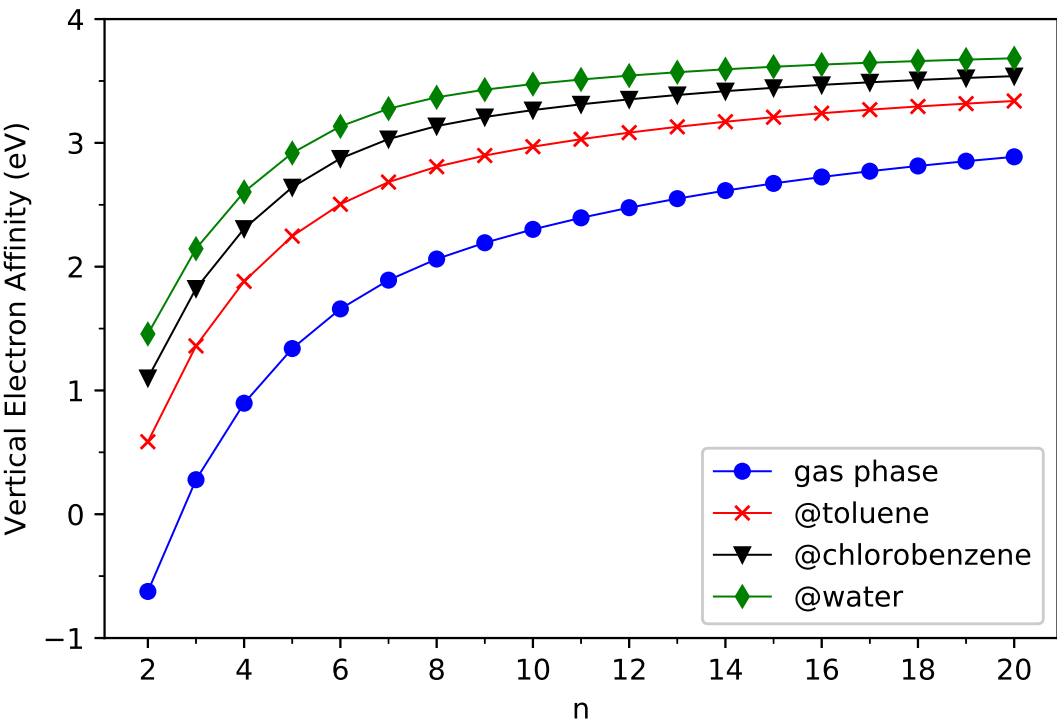


Figure 5. Vertical electron affinity for the ground state of n -acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), calculated using spin-unrestricted TAO-PCM (i.e., TAO-LDA/C-PCM).

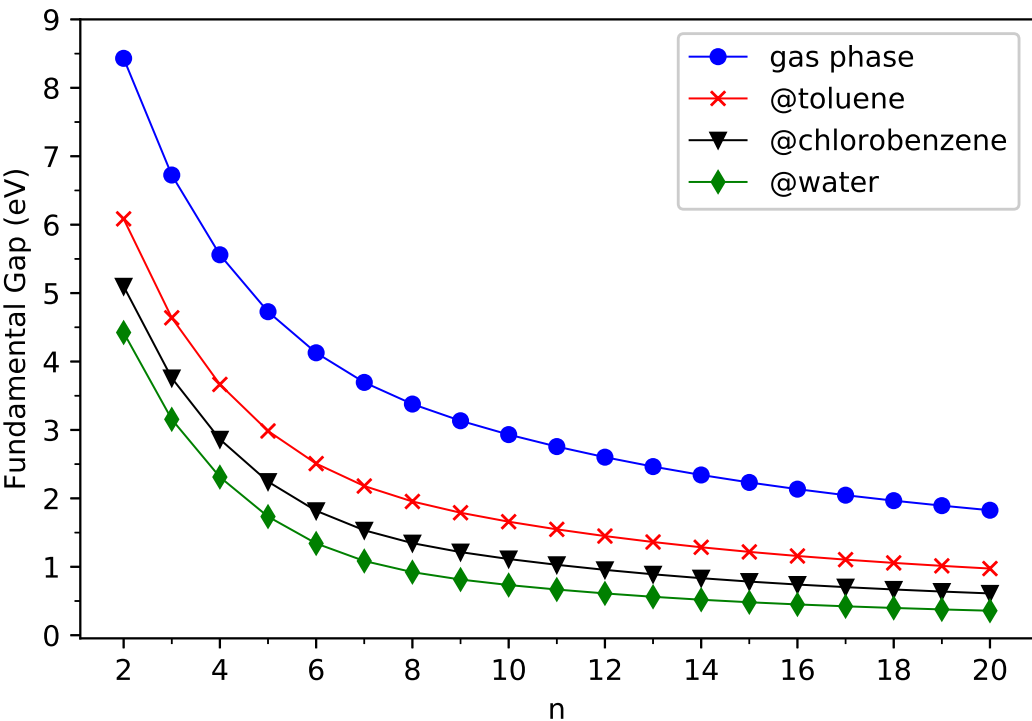


Figure 6. Fundamental gap for the ground state of n -acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), calculated using spin-unrestricted TAO-PCM (i.e., TAO-LDA/C-PCM).

A similar but opposite trend is observed from the EA_v . As the size of n -acene increases, the EA_v increases in a monotonic manner for each solvent studied. In addition, for each n -acene studied, the EA_v increases as the solvent dielectric constant ϵ increases, indicating that more free energy is gained when an electron is added to n -acene in the continuum solvent of larger ϵ . Accordingly, the EA_v of n -acene is the smallest in the gas phase ($\epsilon = 1$), and is the largest in water ($\epsilon = 78.39$).

Because of the monotonically decreasing nature of IP_v and the monotonically increasing nature of EA_v with increasing n -acene size, unsurprisingly, for each solvent studied, the E_g decreases in a monotonic manner with increasing n . Moreover, for each n -acene studied, the E_g decreases as the solvent dielectric constant ϵ increases. Consequently, the E_g of n -acene is the largest in the gas phase ($\epsilon = 1$), and is the smallest in water ($\epsilon = 78.39$).

In short, our study suggests that the solvation effects are rather important in the IP_v , EA_v , and E_g values of ground-state n -acenes, since their values can be easily tuned by changing solvents. This highlights the significance of TAO-PCM in the modeling of solvent effects on the ground-state properties of nanomolecules with MR character.

4.3. Symmetrized von Neumann Entropy

Similar to the TOONs in TAO-DFT [37–39,44], the TOONs in TAO-PCM can be approximately regarded as the natural orbital occupation numbers (NOONs) [76] for the ground state of a solute molecule in the continuum solvent. Hence, the strength of MR character of ground-state n -acene in the continuum solvent can be estimated using the corresponding value of S_{vN} (symmetrized von Neumann entropy) [38,39,77]:

$$S_{vN} = -\frac{1}{2} \sum_i \left\{ f_i \ln(f_i) + (1 - f_i) \ln(1 - f_i) \right\}, \quad (10)$$

where $\{f_i\}$ are the TOONs (see Equation (4)) of ground-state n -acene in the continuum solvent, obtained with spin-unrestricted TAO-PCM (i.e., TAO-LDA/C-PCM). Note that the S_{vN} value is close to 0 for an electronic system with single-reference character (i.e., all the TOONs are very close to either 0 or 1), and can be much larger than 0 for an electronic system with significant MR character (i.e., some of the TOONs considerably deviate from the values of 0 and 1).

As shown in Figure 7 (also see Table S6 in the SI for additional information), the S_{vN} value of ground-state n -acene in the continuum solvent increases with n , implying that the respective strength of MR character should also increase with n . Besides, the S_{vN} values of ground-state n -acenes in three different solvents (toluene, chlorobenzene, and water) are essentially identical to those of ground-state n -acenes in the gas phase [38,39,43,45], suggesting that the solvation effects are unimportant in affecting the S_{vN} values (i.e., a measure of the strength of MR character) of ground-state n -acenes.

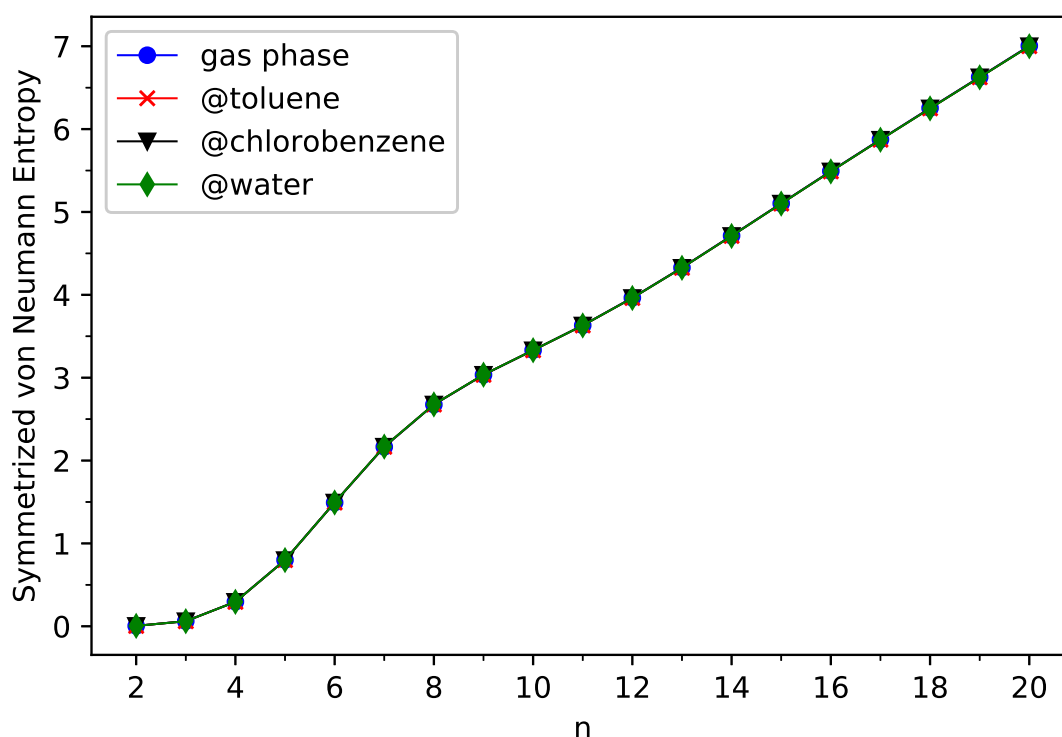


Figure 7. Symmetrized von Neumann entropy for the ground state of n -acene in the gas phase and in three different solvents (toluene, chlorobenzene, and water), calculated using spin-unrestricted TAO-PCM (i.e., TAO-LDA/C-PCM).

4.4. Active TAO-Orbital Occupation Numbers

To see why the aforementioned S_{vN} value increases with n , we reveal the active TOONs of ground-state n -acene (with N electrons) in the continuum solvent, obtained with spin-restricted TAO-PCM (i.e., TAO-LDA/C-PCM). We denote the $(N/2)^{\text{th}}$ TAO-orbital as the highest occupied molecular orbital (HOMO) and the $(N/2 + 1)^{\text{th}}$ TAO-orbital as the lowest unoccupied molecular orbital (LUMO) as convention. Besides, the TAO-orbitals with an occupation number ranging from 0.2 to 1.8 are considered as the active TAO-orbitals.

As plotted in Figure 8, the active TOONs of ground-state n -acene in the continuum solvent possess interesting patterns. First, the smaller n -acenes (e.g., $n < 6$) exhibit nonradical nature, since all the TOONs are in the vicinity of either 0 or 2. Second, as the size of n -acene increases, there are more active TAO-orbitals and/or the active TOONs are closer to 1, showing that the larger ground-state n -acenes in the continuum solvent exhibit increasing polyradical nature. Therefore, there is a transition from the nonradical to polyradical nature of ground-state n -acene in the continuum solvent, causing the increase of S_{vN} with n . Besides, the active TOONs of ground-state n -acenes in three solvents (toluene, chlorobenzene, and water) are essentially the same as those of ground-state n -acenes in the gas phase [37,39,43–45], indicating that the solvation effects are indeed insignificant in changing the MR character of ground-state n -acenes (i.e., showing consistency with the S_{vN} analysis).

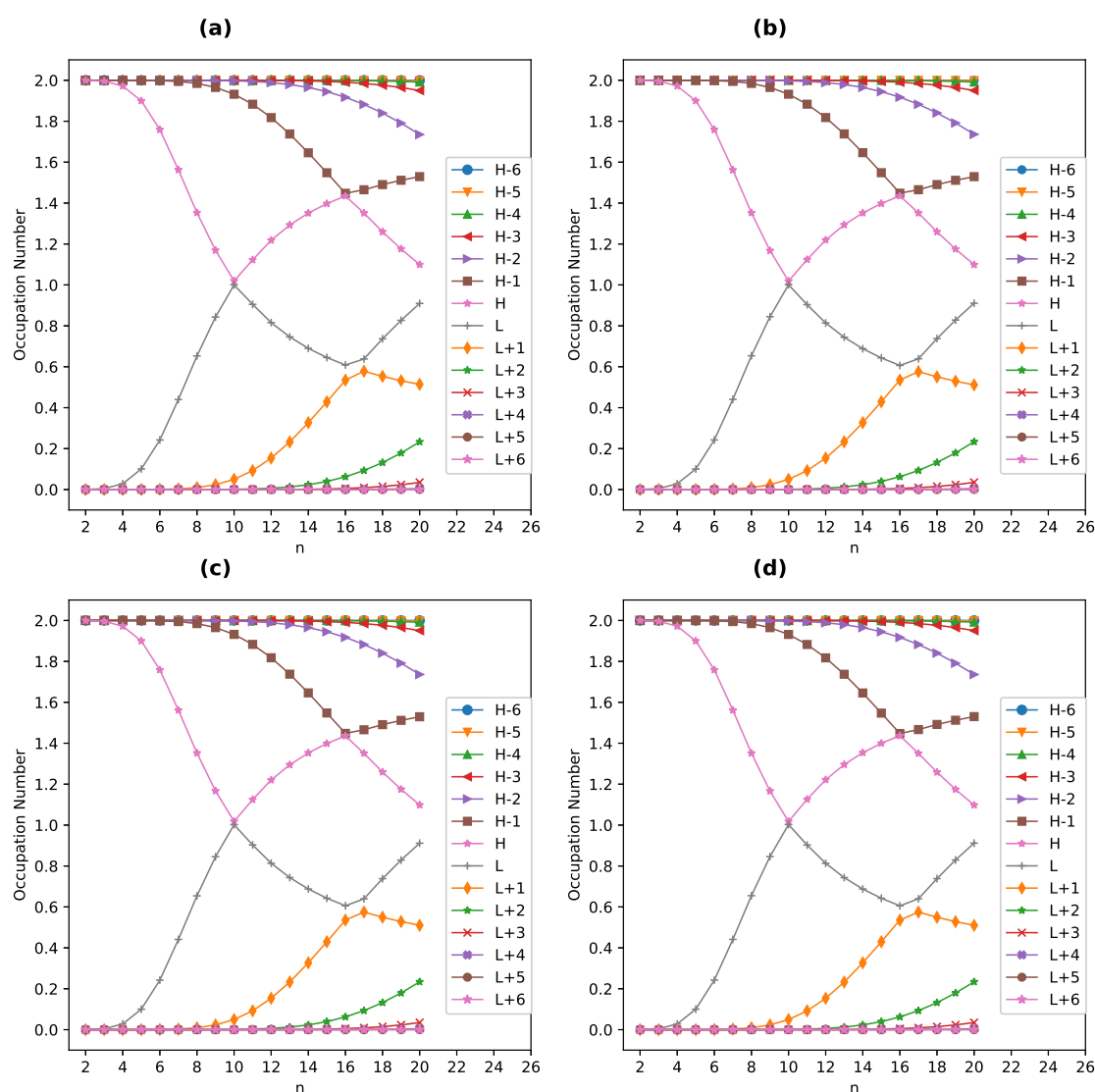


Figure 8. Occupation numbers of active TAO-orbitals (HOMO–6, HOMO–5, ..., HOMO–1, HOMO, LUMO, LUMO+1, ..., LUMO+5, and LUMO+6) for the ground state of n -acene in (a) gas phase and in three different solvents: (b) toluene, (c) chlorobenzene, and (d) water, calculated using spin-restricted TAO-PCM (i.e., TAO-LDA/C-PCM). For brevity, the H/L is used for the HOMO/LUMO.

4.5. Real-Space Representation of Active TAO-Orbitals

As presented in Figures 9 to 11, we reveal the real-space representation of active TAO-orbitals, such as the HOMO and LUMO, for the ground states of some representative n -acenes (e.g., 4-acene, 6-acene, and 8-acene) in the continuum solvent, obtained with spin-restricted TAO-PCM (i.e., TAO-LDA/C-PCM). As n increases, the active TAO-orbitals exhibit an increasing tendency to localize at the edges of n -acene. Besides, since the active TAO-orbitals of ground-state n -acenes in three solvents (toluene, chlorobenzene, and water) look very similar to those of ground-state n -acenes in the gas phase [45], suggesting that the solvation effects play unimportant roles here.

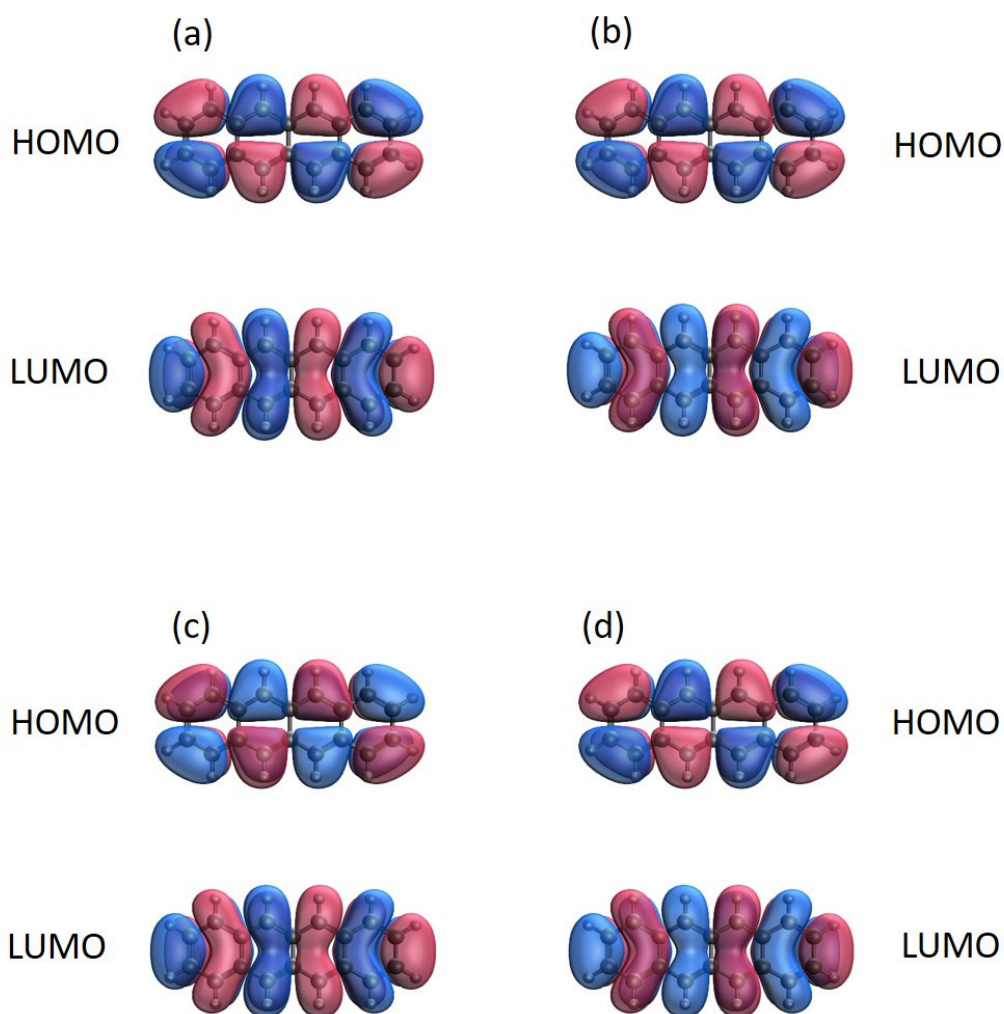


Figure 9. Real-space representation of active TAO-orbitals (HOMO and LUMO) for the ground state of 4-acene in (a) the gas phase and in three different solvents: (b) toluene, (c) chlorobenzene, and (d) water, calculated using spin-restricted TAO-PCM (i.e., TAO-LDA/C-PCM), at an isovalue of $0.02 \text{ e}/\text{\AA}^3$.

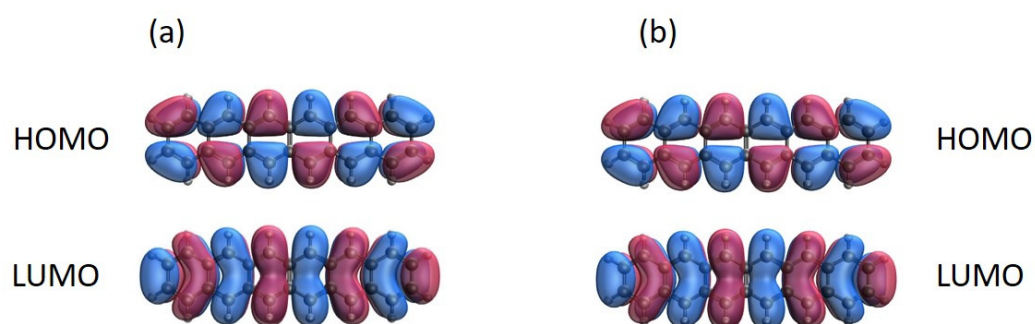


Figure 10. *Cont.*

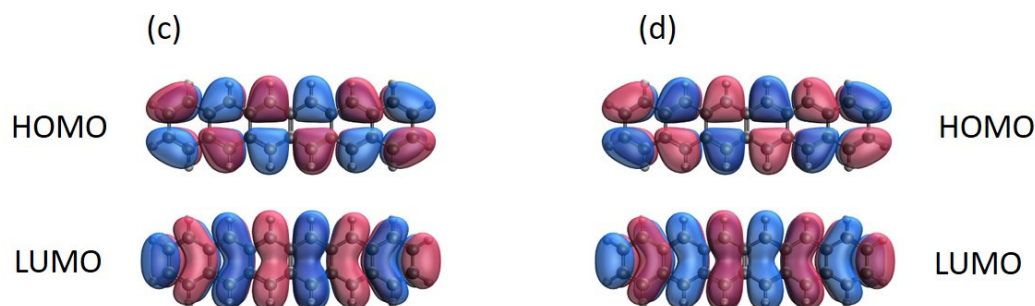


Figure 10. Real-space representation of active TAO-orbitals (HOMO and LUMO) for the ground state of 6-acene in (a) the gas phase and in three different solvents: (b) toluene, (c) chlorobenzene, and (d) water, calculated using spin-restricted TAO-PCM (i.e., TAO-LDA/C-PCM), at an isovalue of $0.02 \text{ e}/\text{\AA}^3$.

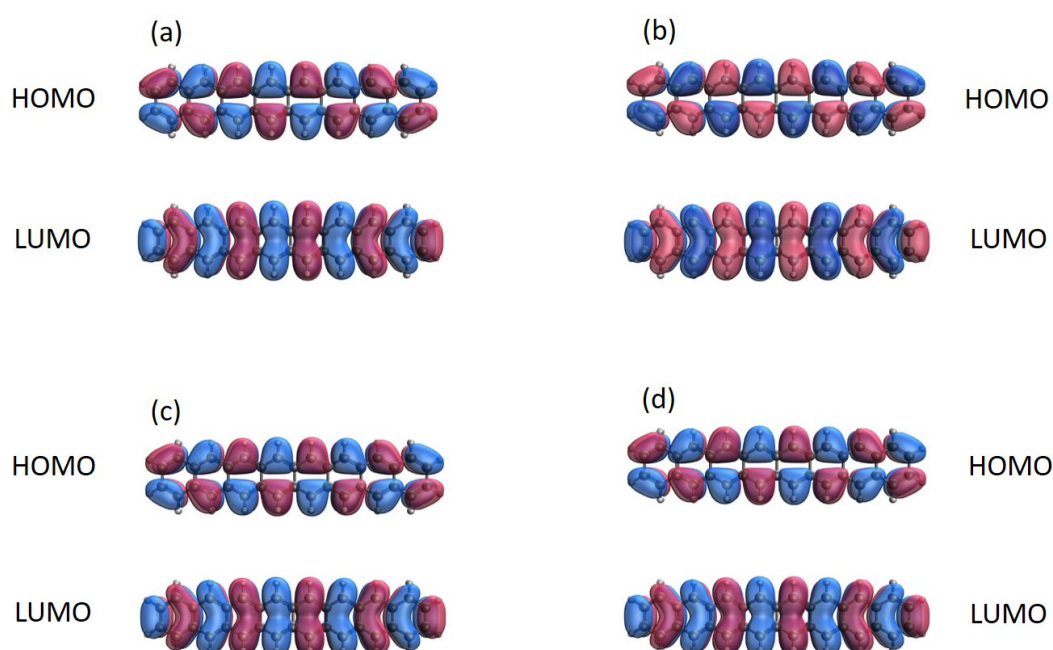


Figure 11. Real-space representation of active TAO-orbitals (HOMO and LUMO) for the ground state of 8-acene in (a) the gas phase and in three different solvents: (b) toluene, (c) chlorobenzene, and (d) water, calculated using spin-restricted TAO-PCM (i.e., TAO-LDA/C-PCM), at an isovalue of $0.02 \text{ e}/\text{\AA}^3$.

5. Conclusions

In conclusion, we have developed TAO-PCM, combining TAO-DFT with the PCM to study solvation effects on the ground-state properties of nanomolecules with MR character at a minimal computational cost. Besides, we have adopted TAO-PCM (i.e., TAO-LDA/C-PCM) to explore the electronic properties (the singlet-triplet gap, vertical electron affinity/ionization potential, fundamental gap, etc.) of n -acene (i.e., the solute) with $n = 2\text{--}20$, in the gas phase and in three different solvents (toluene, chlorobenzene, and water). For comparison, our TAO-PCM results are also compared with the corresponding KS-PCM (i.e., KS-LDA/C-PCM) results.

In the gas phase as well as in the three solvents, since the larger n -acenes have been found to exhibit MR character in the ground states (i.e., the lowest singlet states), KS-PCM can yield incorrect electronic properties. For example, the ground states of some larger n -acenes in different media, obtained with spin-unrestricted KS-PCM, have been found to be highly spin-contaminated, yielding unphysical spin-symmetry breaking effects. While accurate MR electronic structure methods may remedy this issue, these MR methods and related PCMs could be computationally impossible for the

larger n -acenes in the gas phase and solution phase, respectively. Hence, it is well justified to adopt TAO-PCM to explore the electronic properties of n -acenes in different media, because of its decent compromise between accuracy and efficiency.

According to TAO-PCM, in the three solvents, the smaller n -acenes (e.g., $n < 6$) exhibit nonradical nature, and the larger n -acenes exhibit increasing polyradical nature, similar to the previous findings in the gas-phase situations [37–39,43–45]. Also, significant changes in some of the electronic properties (e.g., the vertical electron affinity/ionization potential, and fundamental gap) of ground-state n -acene have been found due to the presence of these solvents, highlighting the importance of TAO-PCM in the modeling of solvent effects on the ground-state properties of nanomolecules with MR character.

While TAO-PCM seems to be promising for the study of solvation effects on the ground-state properties of nanomolecules with MR character, TAO-PCM may not work well in the situations where the underlying PCM (or other implicit solvation models) could fail badly. Therefore, in the near future, we plan to explore the possibility of combining TAO-DFT with an efficient explicit solvent model to resolve this issue.

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